

耐辐射 V 类, 无刷 DC 电机控制

查询样品: [UC1625-SP](#)

特性

- 经QML-V 标准认证, **SMD 5962-91689**
- 耐辐射: **40 kRad (Si) TID** ⁽¹⁾
- 直接驱动功率场效应管 (**MOSFET**) 或者达灵顿功率管 (**Darlington**)
- **50-V** 开路集电极高层驱动器
- 锁存软启动

(1) 辐射容限是基于初始器件鉴定 (放射量率 = 10 mrad/sec) 的典型值。可提供辐射批量接受测试——详情请与厂家联系。

- 装有理想二极管的高速电流感应放大器
- 逐脉冲和平均电流感应
- 过压及欠压保护
- 用于安全方向反转的方向门
- 转速计
- 修整参考源 **30 mA**
- 可编程交叉传导保护
- 两象限和四象限运算

说明/订购信息

UC1625 电机控制器在一个封装内集成了高性能无刷dc电机控制所需的大多数功能。当与外部功率场效应管 (MOSFET) 或者达灵顿功率管 (Darlington) 耦合的时候, 此器件在电压或者电流模式下件执行固定频率PWM 电机控制的同时执行闭环速度控制和具有智能噪音抑制功能的刹车, 安全方向反转, 和交叉传导保护。

虽然额定工作电压范围是 10 V至 18V, UC1625 可借助于外部电平位移组件来控制具有更高电源电压的器件。

UC1625 含有用于低侧功率器件的快速、高电流推挽驱动器和用于高侧功率器件或者电平位移电路的 50 V开路集电极输出。

UC1625 额定军用工作温度范围是 -55°C 至 125°C。

ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-55°C to 125°C	CDIP – JT	5962-9168902VYA	5962-9168902VYA UC1625-SP

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

over operating free-air temperature range (unless otherwise noted)

- (1) Currents are positive into and negative out of the specified terminal.
- (2) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only and functional operation of the device at these or any other conditions beyond those specified is not implied.

RECOMMENDED OPERATING CONDITIONS

over operating temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{CC}	Supply Voltage	10		18	V
PU	Output Current			+85 continuous	mA
PD				±85 continuous	mA
T _A	Operating temperature range	-55		125	°C

Table 1. THERMAL RATINGS TABLE

PACKAGE	R _{θJA} (°C/W) (Junction-to-ambient thermal resistance)	R _{θJC} (°C/W) (Junction-to-case thermal resistance)
DIL-28 (JT)	43.1	4.95

Figure 1. CONNECTION DIAGRAM


UC1625-SP

ZHCS012A – SEPTEMBER 2011 – REVISED SEPTEMBER 2011

www.ti.com.cn

ELECTRICAL CHARACTERISTICS

Unless otherwise stated, these specifications apply over the full temperature range, typical values at $T_A = 25^\circ\text{C}$; Pwr $V_{CC} = V_{CC} = 12\text{ V}$; $R_{OSC} = 20\text{ k}\Omega$ to V_{REF} ; $C_{OSC} = 2\text{ nF}$; $R_{TACH} = 33\text{ k}\Omega$; $C_{TACH} = 10\text{ nF}$; and all outputs unloaded. $T_A = T_J$.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Overall						
	Supply current	-55°C to 125°C		14.5	30.0	mA
	VCC turn-on threshold		8.65	8.95	9.55	V
	VCC turn-off threshold		7.75	8.05	8.55	
Overvoltage/Coast						
	OV-COAST inhibit threshold	-55°C to 125°C	1.65	1.75	1.85	V
	OV-COAST restart threshold		1.535	1.65	1.75	
	OV-COAST hysteresis		0.05	0.10	0.155	
	OV-COAST input current		-10	-1	10	μA
Logic Inputs						
	H1, H2, H3 low threshold	-55°C to 125°C	0.8	1.0	1.25	V
	H1, H2, H3 high threshold		1.6	1.9	2.0	
	H1, H2, H3 input current	-55°C to 125°C, to 0 V	-400	-250	-120	μA
	QUAD SEL, dir thresholds	-55°C to 125°C	0.8	1.4	3.0	V
	QUAD SEL hysteresis			70	130	mV
	DIR hysteresis		0.4	0.6	0.9	V
	QUAD SEL input current		-30	50	150	μA
	DIR input current		-30	-1	30	
PWM Amp/Comparator						
	E/A IN(+), E/A IN(-) input current	To 2.5 V	-5.0	-0.1	5.0	μA
	PWM IN input current	To 2.5 V	0	3	30	
	Error amp input offset	0 V < V _{COMMON-MODE} < 3 V	-10		10	mV
	Error amp voltage gain		70	90		dB
	E/A OUT range	25°C to 125°C	0.25		3.50	V
		-55°C	0.25		4.2	
S _{START}	Pullup current	To 0 V, 25°C	-16	-10	-5	μA
		To 0 V , -55°C to 125°C	-17.5		-5	
	Discharge current	To 2.5 V	0.1	0.4	3.0	mA
	Restart threshold		0.1	0.2	0.3	V
Current Amp						
	Gain	I _{SENSE1} = 0.3 V, I _{SENSE2} = 0.5 V to 0.7 V	1.75	1.95	2.15	V/V
	Level shift	I _{SENSE1} = 0.3 V, I _{SENSE2} = 0.3 V	2.4	2.5	2.65	V
	Peak current threshold	I _{SENSE1} = 0 V, force I _{SENSE2}	0.14	0.20	0.26	
	Over current threshold		0.26	0.30	0.36	
	I _{SENSE1} , I _{SENSE2} input current	To 0 V	-850	-320	0	μA
	I _{SENSE1} , I _{SENSE2} offset current		-12	±2	12	
	Range I _{SENSE1} , I _{SENSE2}		-1		2	
Tachometer/Brake						
	TACH-OUT high level	-55°C to 125°C, 10 kΩ to 2.5 V	4.7	5	5.3	V
	TACH-OUT low level				0.2	
	On time		170	220	280	μs
	On time change with temp	-55°C to 125°C		0.1%		
	RC-BRAKE input current	To 0 V	-4.0	-1.9		mA

ELECTRICAL CHARACTERISTICS (continued)

Unless otherwise stated, these specifications apply over the full temperature range, typical values at $T_A = 25^\circ\text{C}$; $P_{wr} V_{CC} = V_{CC} = 12\text{ V}$; $R_{OSC} = 20\text{ k}\Omega$ to V_{REF} ; $C_{OSC} = 2\text{ nF}$; $R_{TACH} = 33\text{ k}\Omega$; $C_{TACH} = 10\text{ nF}$; and all outputs unloaded. $T_A = T_J$.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Threshold to brake, RC-brake	-55°C to 125°C	0.8	1.0	1.2	V
	Brake hysteresis, RC-brake			0.09	0.4	
	SPEED-IN threshold		220	257	290	mV
	SPEED-IN input current		-30	-5	30	µA
Low-Side Drivers ⁽¹⁾						
	Voh, -1 mA, down from VCC	-55°C to 125°C		1.60	2.50	V
	Voh, -50 mA, down from VCC			1.75	2.45	
	Vol, 1 mA			0.05	0.4	
	Vol, 50 mA			0.36	0.9	
	Rise/fall time	10% to 90% slew time, into 1 nF		50	500	ns
High-Side Drivers						
	Vol, 1 mA	-55°C to 125°C		0.1	0.4	V
	Vol, 50 mA			1.0	1.8	
	Leakage current	Output voltage = 50 V			30	µA
	Fall time	10% to 90% slew time, 50 mA load		50		ns
Oscillator						
	Frequency	-55°C to 125°C	30		80	kHz
Reference						
	Output voltage	Iref = 0 mA, 25°C	4.85	5.0	5.15	V
		-55°C to 125°C	4.7	5.0	5.3	
	Load regulation	0 mA to -20 mA load	-40	-5		mV
	Line regulation	10 V to 18 V VCC	-10	-1	10	
	Short circuit current	-55°C to 125°C	20	100	150	mA
Miscellaneous						
	Output turn-on delay			1		µs
	Output turn-off delay			1		

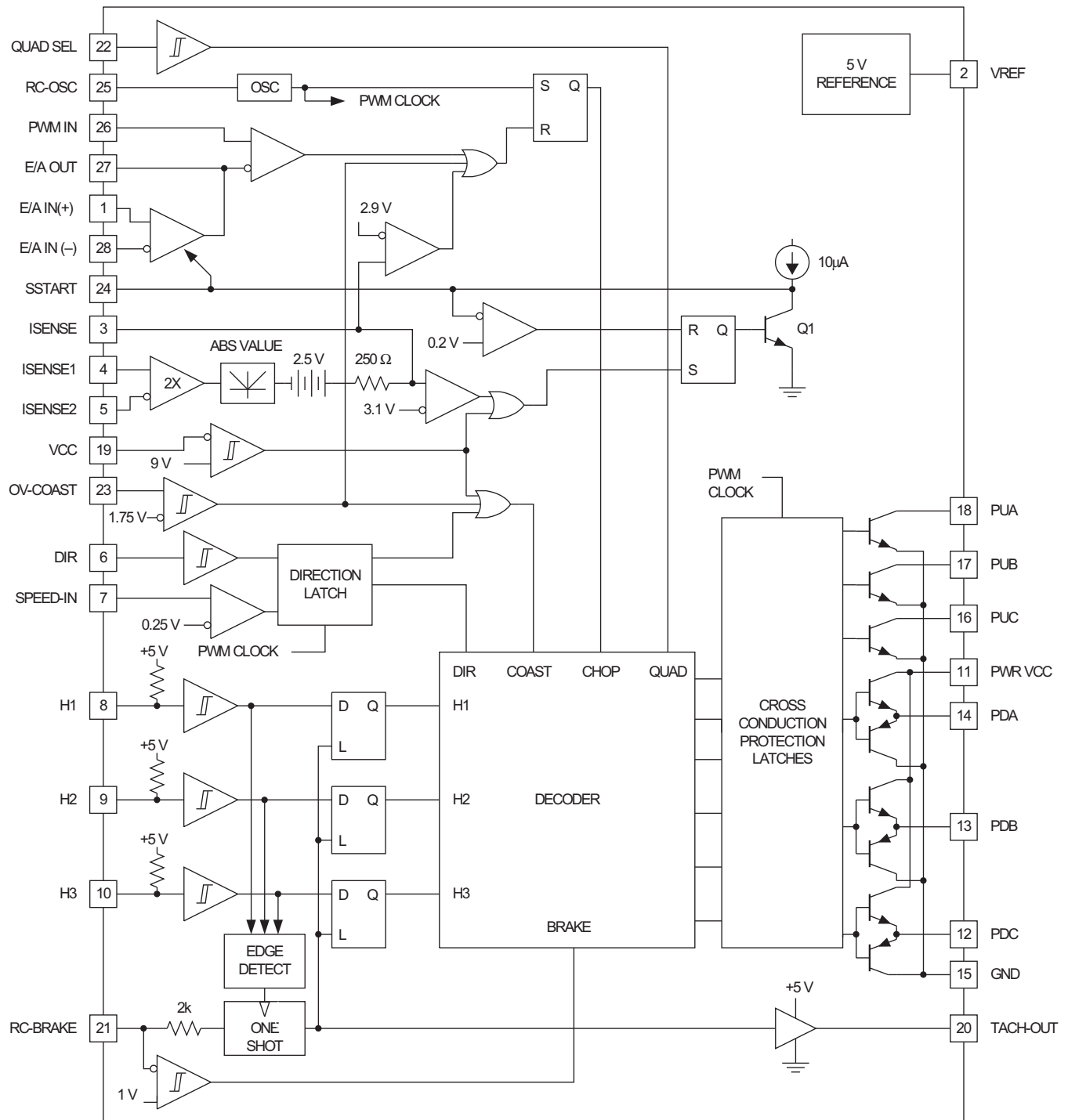
(1) Current available from these pins can peak as high as 0.5 A.

UC1625-SP

ZHCS012A – SEPTEMBER 2011 – REVISED SEPTEMBER 2011

www.ti.com.cn

Block Diagram



DEVICE INFORMATION

Terminal Functions

TERMINAL		DESCRIPTION
NAME	NO.	
DIR, SPEED-IN	6, 7	The position decoder logic translates the Hall signals and the DIR signal to the correct driver signals (PUs and PDs). To prevent output stage damage, the signal on DIR is first loaded into a direction latch, then shifted through a two-bit register. As long as SPEED-IN is less than 250 mV, the direction latch is transparent. When SPEED-IN is higher than 250 mV, the direction latch inhibits all changes in direction. SPEED-IN can be connected to TACH-OUT through a filter, so that the direction latch is only transparent when the motor is spinning slowly, and has too little stored energy to damage power devices. Additional circuitry detects when the input and output of the direction latch are different, or when the input and output of the shift register are different, and inhibits all output drives during that time. This can be used to allow the motor to coast to a safe speed before reversing. The shift register ensures that direction can not be changed instantaneously. The register is clocked by the PWM oscillator, so the delay between direction changes is always going to be between one and two oscillator periods. At 40 kHz, this corresponds to a delay of between 25 µs and 50 µs. Regardless of output stage, 25 µs deadtime should be adequate to ensure no overlap cross-conduction. Toggling DIR causes an output pulse on TACH-OUT regardless of motor speed.
E/A IN(+), E/A IN(–), E/A OUT, PWM IN	1, 28, 27, 26	E/A IN(+) and E/A IN(–) are not internally committed to allow for a wide variety of uses. They can be connected to the ISENSE, to TACH-OUT through a filter, to an external command voltage, to a D/A converter for computer control, or to another op amp for more elegant feedback loops. The error amplifier is compensated for unity gain stability, so E/A OUT can be tied to E/A IN(–) for feedback and major loop compensation. E/A OUT and PWM IN drive the PWM comparator. For voltage-mode PWM systems, PWM IN can be connected to RC-OSC. The PWM comparator clears the PWM latch, commanding the outputs to chop. The error amplifier can be biased off by connecting E/A IN(–) to a higher voltage than E/A IN(+). When biased off, E/A OUT appears to the application as a resistor to ground. E/A OUT can then be driven by an external amplifier.
GND	15	All thresholds and outputs are referred to the GND pin except for the PD and PU outputs.
H1, H2, H3	8, 9, 10	The three shaft position sensor inputs consist of hysteresis comparators with input pullup resistors. Logic thresholds meet TTL specifications and can be driven by 5-V CMOS, 12-V CMOS, NMOS, or open-collectors. Connect these inputs to motor shaft position sensors that are positioned 120 electrical degrees apart. If noisy signals are expected, zener clamp and filter these inputs with 6-V zeners and an RC filter. Suggested filtering components are 1 kΩ and 2 nF. Edge skew in the filter is not a problem, because sensors normally generate modified gray code with only one output changing at a time, but rise and fall times must be shorter than 20 µs for correct tachometer operation. Motors with 60 electrical degree position sensor coding can be used if one or two of the position sensor signals is inverted.
ISENSE1, ISENSE2, ISENSE	3, 4, 5	The current sense amplifier has a fixed gain of approximately two. It also has a built-in level shift of approximately 2.5 V. The signal appearing on ISENSE is: $I_{SENSE} = 2.5 \text{ V} + (2 \times \text{ABS} (I_{SENSE1} - I_{SENSE2}))$ I_{SENSE1} and I_{SENSE2} are interchangeable and can be used as differential inputs. The differential signal applied can be as high as ±0.5 V before saturation. If spikes are expected on ISENSE1 or ISENSE2, they are best filtered by a capacitor from ISENSE to ground. Filtering this way allows fast signal inversions to be correctly processed by the absolute value circuit. The peak-current comparator allows the PWM to enter a current-limit mode with current in the windings never exceeding approximately 0.2 V / R_{SENSE}. The overcurrent comparator provides a fail-safe shutdown in the unlikely case of current exceeding 0.3 V / R_{SENSE}. Then, softstart is commanded, and all outputs are turned off until the high current condition is removed. It is often essential to use some filter driving ISENSE1 and ISENSE2 to reject extreme spikes and to control slew rate. Reasonable starting values for filter components might be 250-Ω series resistors and a 5-nF capacitor between ISENSE1 and ISENSE2. Input resistors should be kept small and matched to maintain gain accuracy.
OV-COAST	23	This input can be used as an over-voltage shut-down input, as a coast input, or both. This input can be driven by TTL, 5-V CMOS, or 12-V CMOS.

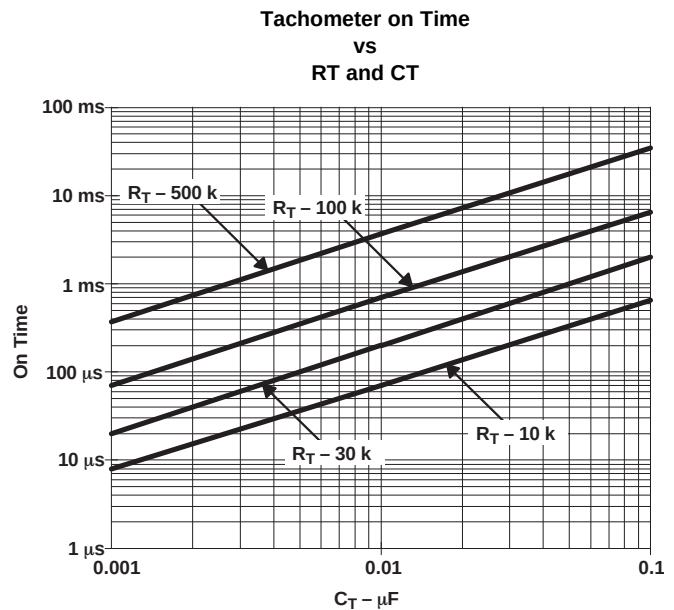
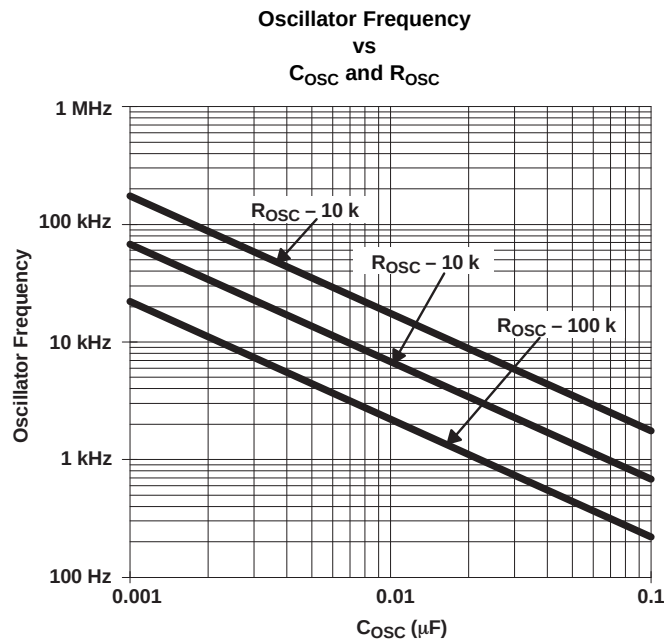
Terminal Functions (continued)

TERMINAL		DESCRIPTION
NAME	NO.	
PDA, PDB, PDC	12, 13, 14	These outputs can drive the gates of N-channel power MOSFETs directly or they can drive the bases of power Darlington's if some form of current limiting is used. They are meant to drive low-side power devices in high-current output stages. Current available from these pins can peak as high as 0.5 A. These outputs feature a true totem-pole output stage. Beware of exceeding device power dissipation limits when using these outputs for high continuous currents. These outputs pull high to turn a "low-side" device on (active high).
PUA, PUB, PUC	16, 17, 18	These outputs are open-collector, high-voltage drivers that are meant to drive high-side power devices in high-current output stages. These are active low outputs, meaning that these outputs pull low to command a high-side device on. These outputs can drive low-voltage PNP Darlington's and P-channel MOSFETs directly, and can drive any high-voltage device using external charge pump techniques, transformer signal coupling, cascode level-shift transistors, or opto-isolated drive (high-speed opto devices are recommended). (See applications).
PWR VCC	11	This supply pin carries the current sourced by the PD outputs. When connecting PD outputs directly to the bases of power Darlington's, the PWR VCC pin can be current limited with a resistor. Darlington outputs can also be "Baker Clamped" with diodes from collectors back to PWR VCC. (See Applications)
QUAD SEL	22	The device can chop power devices in either of two modes, referred to as "two-quadrant" (Quad Sellow) and "four quadrant" (Quad Sel high). When two-quadrant chopping, the pulldown power devices are chopped by the output of the PWM latch while the pullup drivers remain on. The load chops into one commutation diode, and except for back-EMF, will exhibit slow discharge current and faster charge current. Two-quadrant chopping can be more efficient than four-quadrant. When four-quadrant chopping, all power drivers are chopped by the PWM latch, causing the load current to flow into two diodes during chopping. This mode exhibits better control of load current when current is low, and is preferred in servo systems for equal control over acceleration and deceleration. The QUAD SEL input has no effect on operation during braking.
RC-BRAKE	21	Each time the TACH-OUT pulses, the capacitor tied to RC-BRAKE discharges from approximately 3.33 V down to 1.67 V through a resistor. The tachometer pulse width is approximately $T = 0.67 R_T C_T$, where R_T and C_T are a resistor and capacitor from RC-BRAKE to ground. Recommended values for R_T are 10 k Ω to 500 k Ω , and recommended values for C_T are 1 nF to 100 nF, allowing times between 5 μ s and 10 ms. Best accuracy and stability are achieved with values in the centers of those ranges. RC-BRAKE also has another function. If RC-BRAKE pin is pulled below the brake threshold, the device enters brake mode. This mode consists of turning off all three high-side devices, enabling all three low-side devices, and disabling the tachometer. The only things that inhibit low-side device operation in braking are low-supply, exceeding peak current, OV-COAST command, and the PWM comparator signal. The last of these means that if current sense is implemented such that the signal in the current sense amplifier is proportional to braking current, the low-side devices will brake the motor with current control. (See applications) Simpler current sense connections results in uncontrolled braking and potential damage to the power devices.
RC-OSC	25	The UC1625 can regulate motor current using fixed-frequency pulse width modulation (PWM). The RC-OSC pin sets oscillator frequency by means of timing resistor R_{OSC} from the RC-OSC pin to VREF and capacitor C_{OSC} from RC-OSC to Gnd. Resistors 10 k Ω to 100 k Ω and capacitors 1 nF to 100 nF works the best, but frequency should always be below 500 kHz. Oscillator frequency is approximately: $F = 2 / (R_{OSC} \times C_{OSC})$ Additional components can be added to this device to cause it to operate as a fixed off-time PWM rather than a fixed frequency PWM, using the RC-OSC pin to select the monostable time constant. The voltage on the RC-OSC pin is normally a ramp of about 1.2 V peak-to-peak, centered at approximately 1.6 V. This ramp can be used for voltage-mode PWM control, or can be used for slope compensation in current-mode control.

Terminal Functions (continued)

TERMINAL		DESCRIPTION
NAME	NO.	
SSTART	24	Any time that VCC drops below threshold or the sensed current exceeds the over-current threshold, the soft-start latch is set. When set, it turns on a transistor that pulls down on SSTART. Normally, a capacitor is connected to this pin, and the transistor will completely discharge the capacitor. A comparator senses when the NPN transistor has completely discharged the capacitor, and allows the soft-start latch to clear when the fault is removed. When the fault is removed, the soft-start capacitor charges from the on-chip current source. SSTART clamps the output of the error amplifier, not allowing the error amplifier output voltage to exceed SSTART regardless of input. The ramp on RC-OSC can be applied to PWM In and compared to E/A OUT. With SSTART discharged below 0.2 V and the ramp minimum being approximately 1.0 V, the PWM comparator keeps the PWM latch cleared and the outputs off. As SSTART rises, the PWM comparator begins to duty-cycle modulate the PWM latch until the error amplifier inputs overcome the clamp. This provides for a safe and orderly motor start-up from an off or fault condition. A 51-kΩ resistor is added between VREF and SSTART to ensure switching.
TACH-OUT	20	Any change in the H1, H2, or H3 inputs loads data from these inputs into the position sensor latches. At the same time data is loaded, a fixed-width 5-V pulse is triggered on TACH-OUT. The average value of the voltage on TACH-OUT is directly proportional to speed, so this output can be used as a true tachometer for speed feedback with an external filter or averaging circuit which usually consists of a resistor and capacitor. Whenever TACH-OUT is high, the position latches are inhibited, such that during the noisiest part of the commutation cycle, additional commutations are not possible. Although this effectively sets a maximum rotational speed, the maximum speed can be set above the highest expected speed, preventing false commutation and chatter.
VCC	19	This device operates with supplies between 10 V and 18 V. Under-voltage lockout keeps all outputs off below 7.5 V, insuring that the output transistors never turn on until full drive capability is available. Bypass VCC to ground with an 0.1-μF ceramic capacitor. Using a 10-μF electrolytic bypass capacitor as well can be beneficial in applications with high supply impedance.
VREF	2	This pin provides regulated 5 V for driving Hall-effect devices and speed control circuitry. VREF reaches 5 V before VCC enables, ensuring that Hall-effect devices powered from VREF becomes active before the UC1625 drives any output. For proper performance VREF should be bypassed with at least a 0.1-μF capacitor to ground.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (continued)

**Supply Current
vs
Temperature**

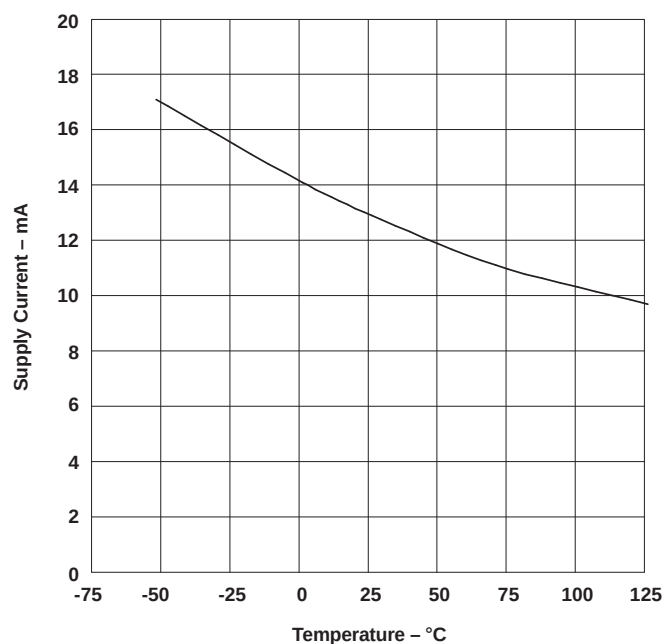


Figure 4.

**Soft-Start Pullup Current
vs
Temperature**

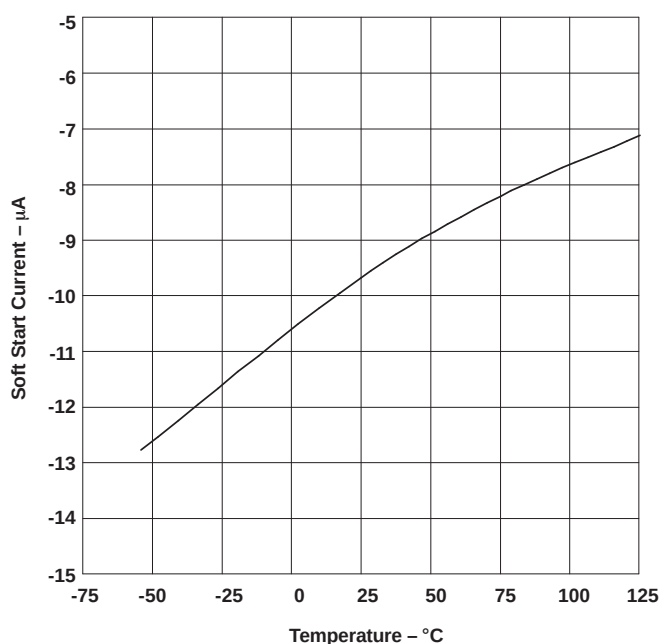


Figure 5.

**Soft-Start Discharge Current
vs
Temperature**

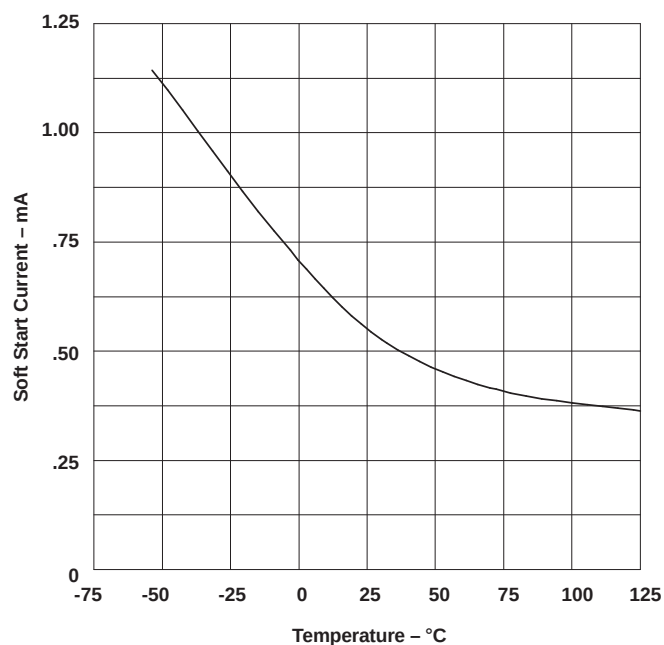


Figure 6.

**Current Sense Amplifier Transfer Function
vs
 $I_{SENSE2} - I_{SENSE1}$**

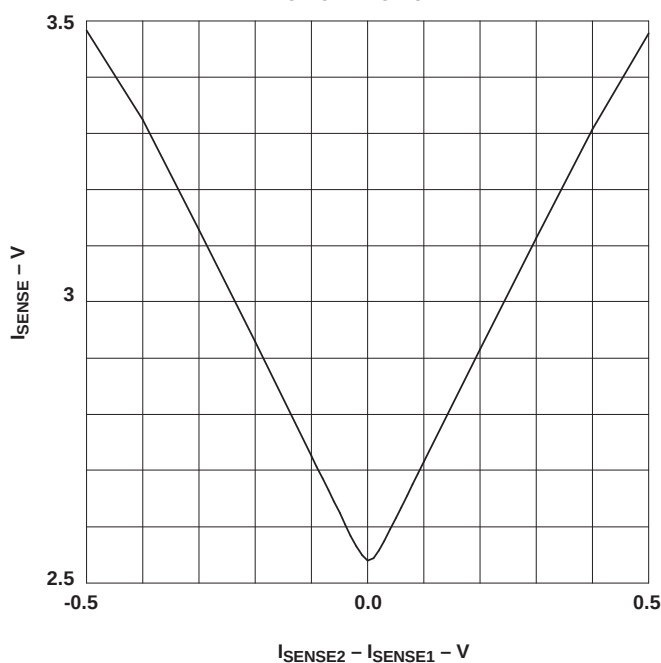


Figure 7.

APPLICATION INFORMATION

Cross Conduction Prevention

The UC1625 inserts delays to prevent cross conduction due to overlapping drive signals. However, some thought must always be given to cross conduction in output stage design because no amount of dead time can prevent fast slewing signals from coupling drive to a power device through a parasitic capacitance.

The UC1625 contains input latches that serve as noise blanking filters. These latches remain transparent through any phase of a motor rotation and latch immediately after an input transition is detected. They remain latched for two cycles of the PWM oscillator. At a PWM oscillator speed of 20 kHz, this corresponds to 50 μ s to 100 μ s of blank time which limits maximum rotational speed to 100 kRPM for a motor with six transitions per rotation or 50 kRPM for a motor with 12 transitions per rotation.

This prevents noise generated in the first 50 μ s of a transition from propagating to the output transistors and causing cross-conduction or chatter.

The UC1625 also contains six flip flops corresponding to the six output drive signals. One of these flip flops is set every time that an output drive signal is turned on, and cleared two PWM oscillator cycles after that drive signal is turned off. The output of each flip flop is used to inhibit drive to the opposing output (Figure 8). In this way, it is impossible to turn on driver PUA and PDA at the same time. It is also impossible for one of these drivers to turn on without the other driver having been off for at least two PWM oscillator clocks.

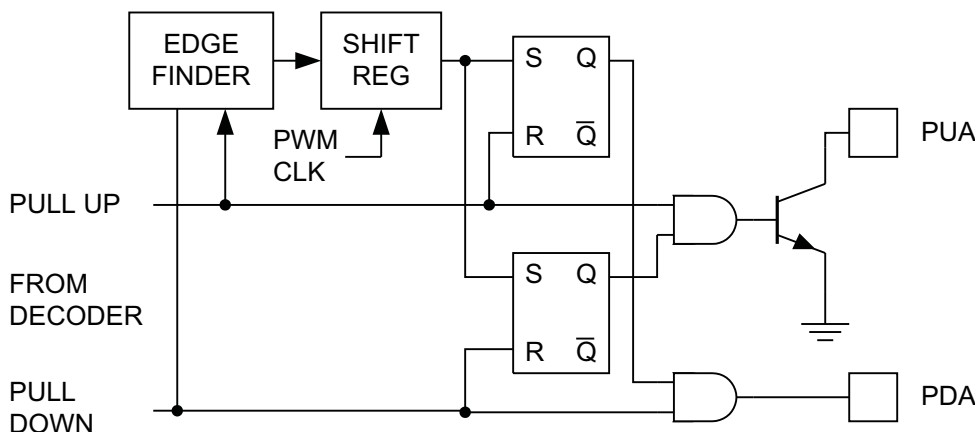


Figure 8. Cross Conduction Prevention

UC1625-SP

ZHCS012A – SEPTEMBER 2011 – REVISED SEPTEMBER 2011

www.ti.com.cn

Power Stage Design

The UC1625 is useful in a wide variety of applications, including high-power in robotics and machinery. The power output stages used in such equipment can take a number of forms, according to the intended performance and purpose of the system. [Figure 9](#) show four different power stages with the advantages and disadvantages of each.

For high-frequency chopping, fast recovery circulating diodes are essential. Six are required to clamp the windings. These diodes should have a continuous current rating at least equal to the operating motor current, since diode conduction duty-cycle can be high. For low-voltage systems, Schottky diodes are preferred. In higher voltage systems, diodes such as Microsemi UHVP high voltage platinum rectifiers are recommended.

In a pulse-by-pulse current control arrangement, current sensing is done by resistor R_S , through which the transistor's currents are passed (Fig. A, B, and C). In these cases, R_D is not needed. The low-side circulating diodes go to ground and the current sense terminals of the UC1625 (I_{SENSE1} and I_{SENSE2}) are connected to R_S through a differential RC filter. The input bias current of the current sense amplifier causes a common mode offset voltage to appear at both inputs, so for best accuracy, keep the filter resistors below 2 k Ω and matched.

The current that flows through R_S is discontinuous because of chopping. It flows during the on time of the power stage and is zero during the off time. Consequently, the voltage across R_S consists of a series of pulses, occurring at the PWM frequency, with a peak value indicative of the peak motor current.

To sense average motor current instead of peak current, add another current sense resistor (R_D in Fig. D) to measure current in the low-side circulating diodes, and operate in four quadrant mode (pin 22 high). The negative voltage across R_D is corrected by the absolute value current sense amplifier. Within the limitations imposed by [Table 2](#), the circuit of Fig. B can also sense average current.

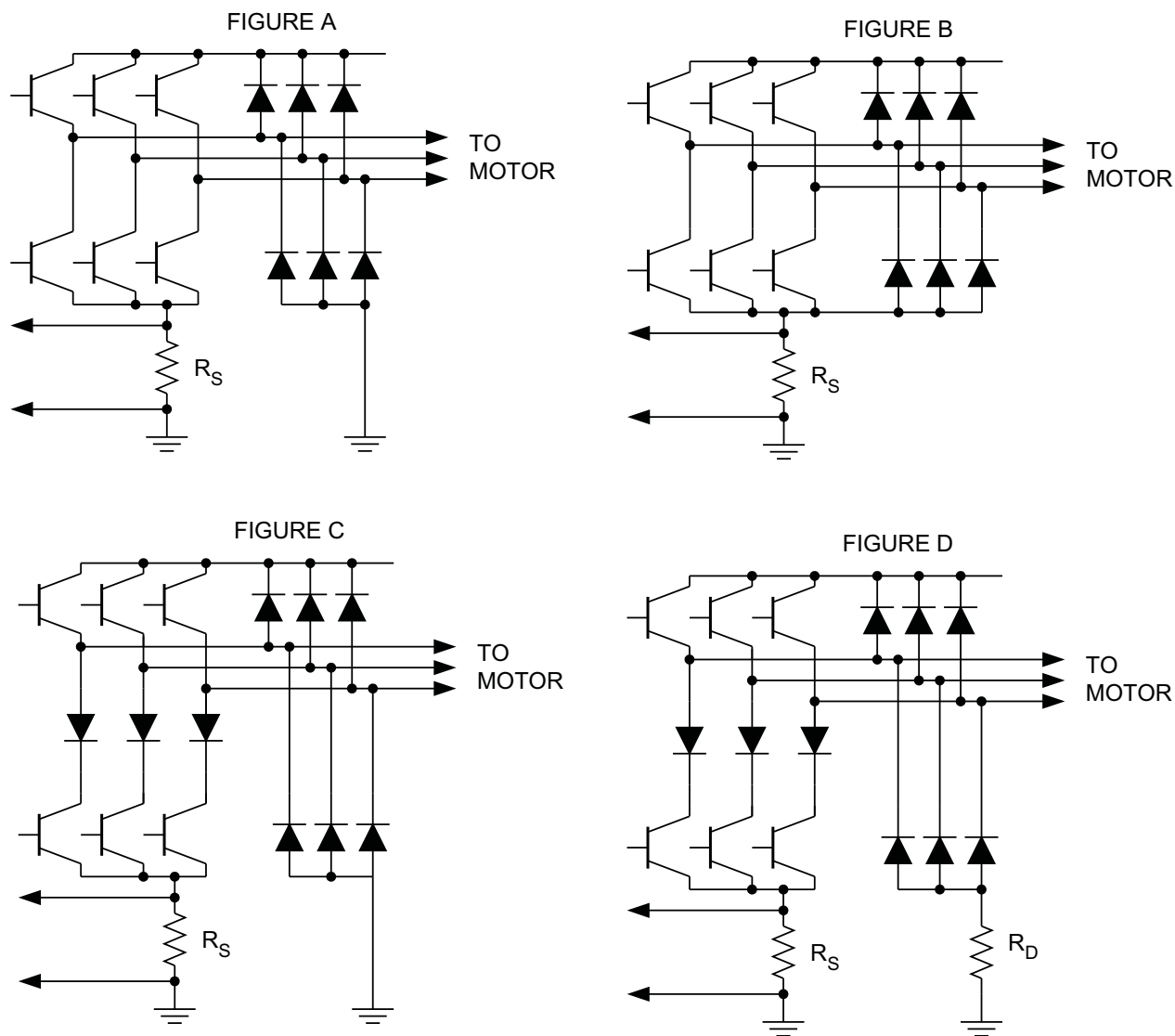


Figure 9. Four Power Stage Designs

Table 2. Imposed Limitations for Figure 9

	2 QUADRANT	4 QUADRANT	SAFE BRAKING	POWER REVERSE	CURRENT SENSE	
					Pulse-by-Pulse	Average
Figure A	Yes	No	No	NO	Yes	No
Figure B	Yes	Yes	No	In 4-quad mode only	Yes	Yes
Figure C	Yes	Yes	Yes	In 4-quad mode only	Yes	No
Figure D	Yes	Yes	Yes	In 4-quad mode only	Yes	Yes

UC1625-SP

ZHCS012A – SEPTEMBER 2011 – REVISED SEPTEMBER 2011

www.ti.com.cn

For drives where speed is critical, P-channel MOSFETs can be driven by emitter followers as shown in [Figure 10](#). Here, both the level shift NPN and the PNP must withstand high voltages. A zener diode is used to limit gate-source voltage on the MOSFET. A series gate resistor is not necessary, but always advisable to control overshoot and ringing.

High-voltage optocouplers can quickly drive high-voltage MOSFETs if a boost supply of at least 10 V greater than the motor supply is provided (See [Figure 11](#)). To protect the MOSFET, the boost supply should not be higher than 18 V above the motor supply.

For under 200-V 2-quadrant applications, a power NPN driven by a small P-Channel MOSFET performs well as a high-side driver as in [Figure 12](#). A high voltage small-signal NPN is used as a level shift and a high voltage low-current MOSFET provides drive. Although the NPN does not saturate if used within its limitations, the base-emitter resistor on the NPN is still the speed-limiting component.

[Figure 13](#) shows a power NPN Darlington drive technique using a clamp to prevent deep saturation. By limiting saturation of the power device, excessive base drive is minimized and turn-off time is kept fairly short. Lack of base series resistance also adds to the speed of this approach.

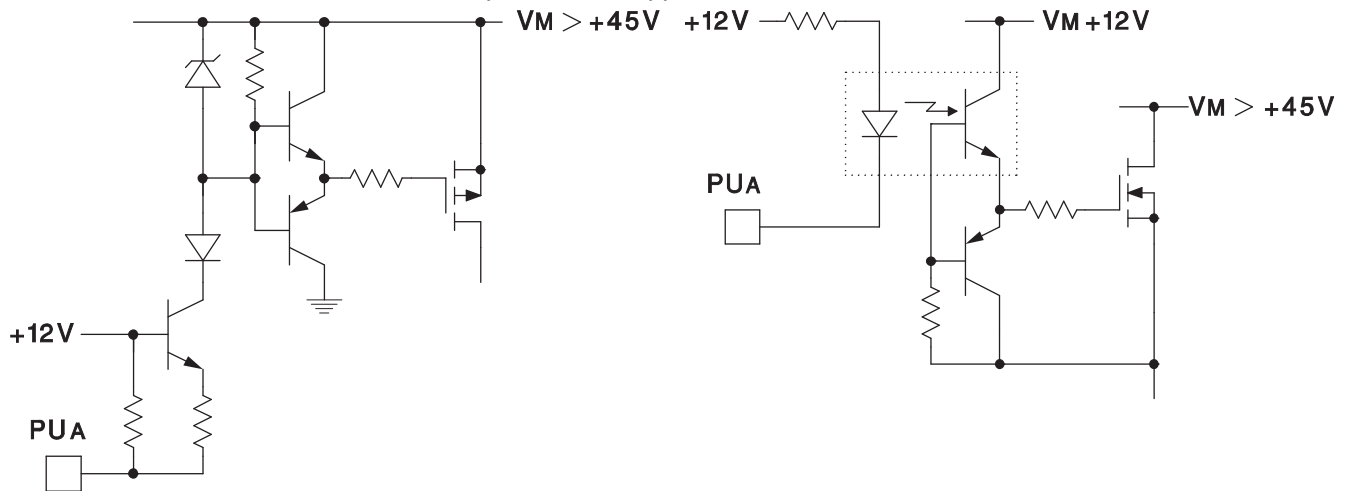


Figure 10. Fast High-Side P-Channel Driver

Figure 11. Optocoupled N-Channel High-Side Driver

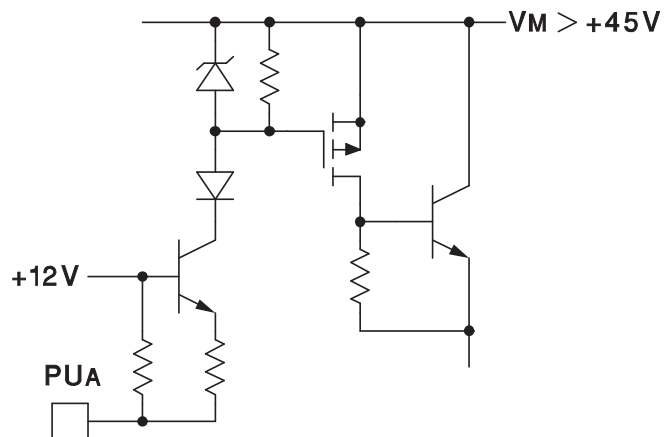


Figure 12. Power NPN High-Side Driver

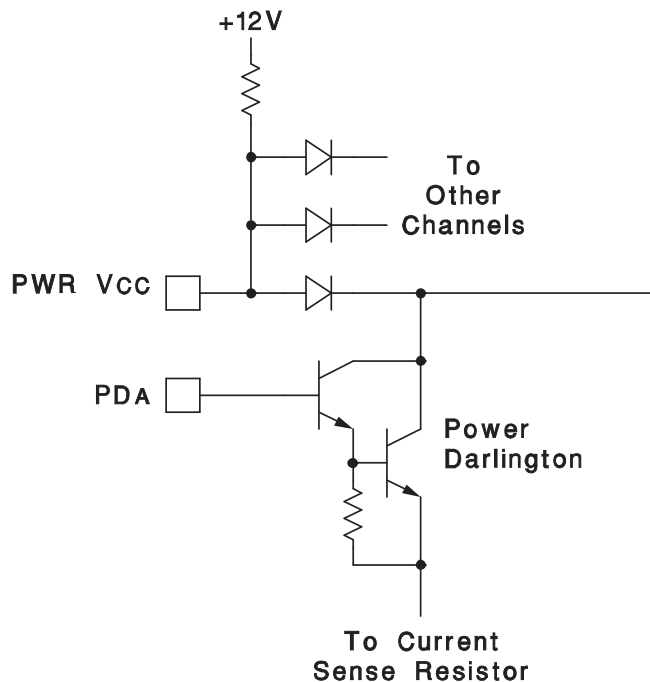


Figure 13. Power NPN Low-Side Driver

UC1625-SP

ZHCS012A – SEPTEMBER 2011 – REVISED SEPTEMBER 2011

www.ti.com.cn

Fast High-Side N-Channel Driver with Transformer Isolation

A small pulse transformer can provide excellent isolation between the UC1625 and a high-voltage N-Channel MOSFET while also coupling gate drive power. In this circuit (shown in Figure 14), a UC3724 is used as a transformer driver/encoder that duty-cycle modulates the transformer with a 150-kHz pulse train. The UC3725 rectifies this pulse train for gate drive power, demodulates the signal, and drives the gate with over 2-A peak current.

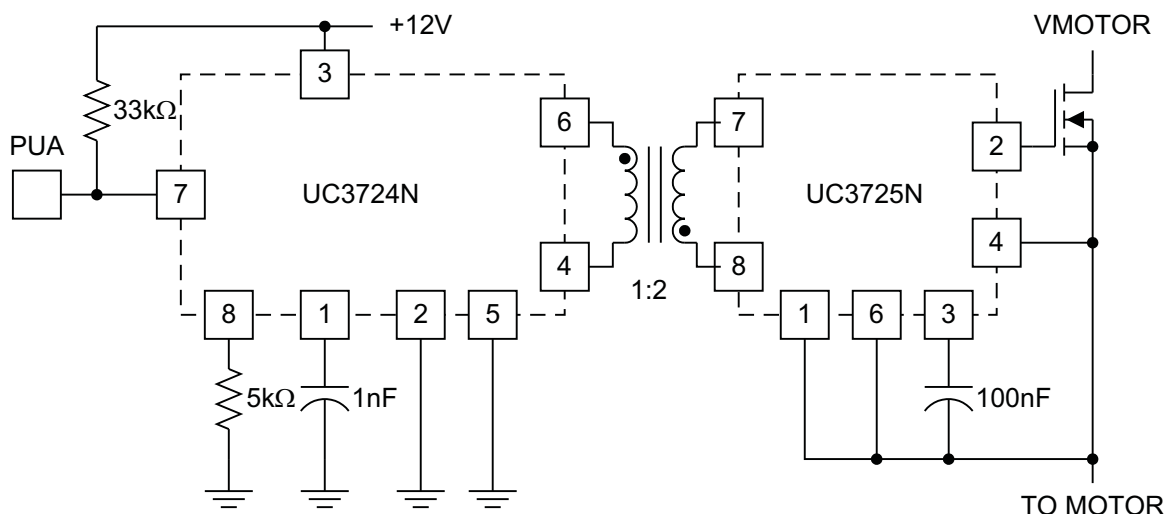


Figure 14. Fast High-Side N-Channel Driver with Transformer Isolation

Both the UC3724 and the UC3725 can operate up to 500 kHz if the pulse transformer is selected appropriately. To raise the operating frequency, either lower the timing resistor of the UC3724 (1 kΩ min), lower the timing capacitor of the UC3724 (500 pF min) or both.

If there is significant capacitance between transformer primary and secondary, together with very high output slew rate, then it may be necessary to add clamp diodes from the transformer primary to 12 V and ground. General purpose small signal switching diodes such as 1N4148 are normally adequate.

The UC3725 also has provisions for MOSFET current limiting. See the UC3725 data sheet for more information on implementing this.

Computational Truth Table

Table 3 shows the outputs of the gate drive and open collector outputs for given hall input codes and direction signals. Numbers at the top of the columns are pin numbers.

These devices operate with position sensor encoding that has either one or two signals high at a time, never all low or all high. This coding is sometimes referred to as "120° Coding" because the coding is the same as coding with position sensors spaced 120 magnetic degrees about the rotor. In response to these position sense signals, only one low-side driver turns on (go high) and one high-side driver turns on (pull low) at any time.

Table 3. Computational Truth Table

INPUTS				OUTPUTS					
DIR	H1	H2	H3	Low-Side			High-Side		
6	8	9	10	12	13	14	16	17	18
1	0	0	1	L	H	L	L	H	H
1	0	1	1	L	L	H	L	H	H
1	0	1	0	L	L	H	H	L	H
1	1	1	0	H	L	L	H	L	H
1	1	0	0	H	L	L	H	H	L
1	1	0	1	L	H	L	H	H	L
0	1	0	1	L	L	H	H	L	H
0	1	0	0	L	L	H	L	H	H
0	1	1	0	L	H	L	L	H	H
0	0	1	0	L	H	L	H	H	L
0	0	1	1	H	L	L	H	H	L
0	0	0	1	H	L	L	H	L	H
X	1	1	1	L	L	L	H	H	H
X	0	0	0	L	L	L	H	H	H

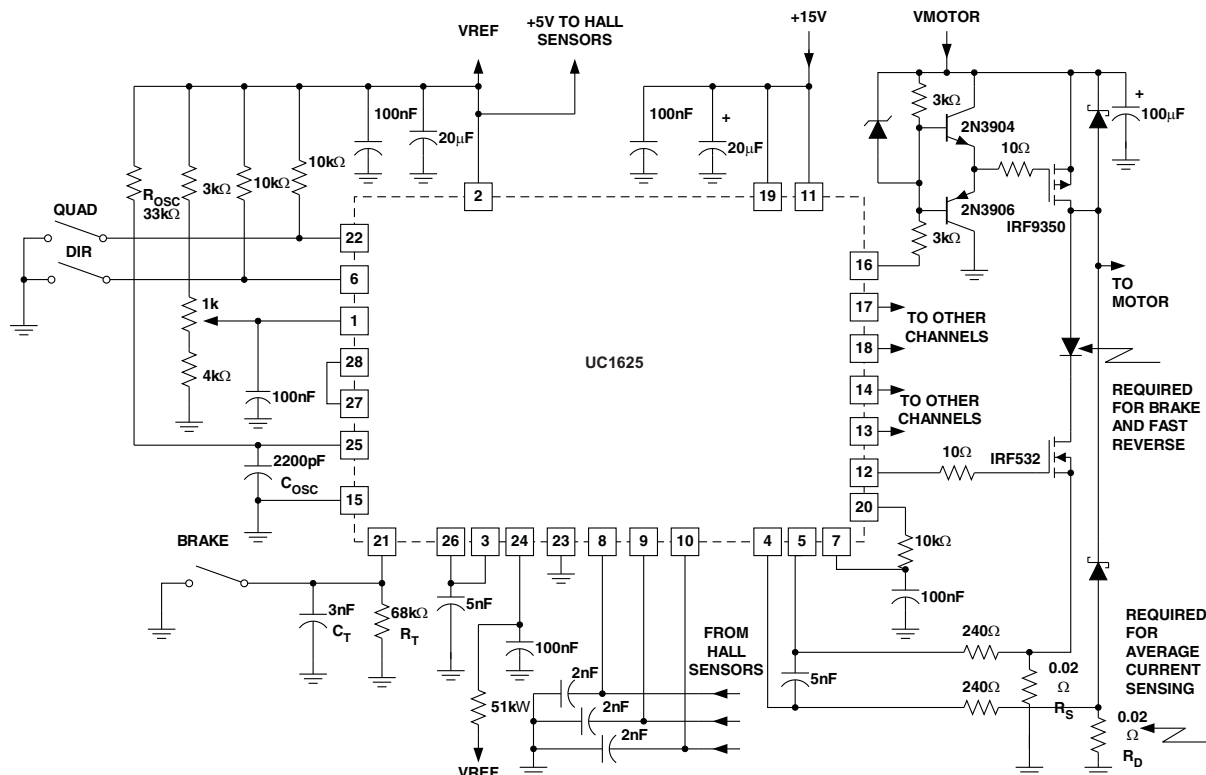


Figure 15. 45-V/8-A Brushless DC Motor Drive Circuit

N-Channel power MOSFETs are used for low-side drivers, while P-Channel power MOSFETs are shown for high-side drivers. Resistors are used to level shift the UC1625 open-collector outputs, driving emitter followers into the MOSFET gate. A 12-V zener clamp insures that the MOSFET gate-source voltage never exceeds 12 V. Series 10- Ω gate resistors tame gate reactance, preventing oscillations and minimizing ringing.

The oscillator timing capacitor should be placed close to pins 15 and 25, to keep ground current out of the capacitor. Ground current in the timing capacitor causes oscillator distortion and slaving to the commutation signal.

The potentiometer connected to pin 1 controls PWM duty cycle directly, implementing a crude form of speed control. This control is often referred to as "voltage mode" because the potentiometer position sets the average motor voltage. This controls speed because steady-state motor speed is closely related to applied voltage.

Pin 20 (Tach-Out) is connected to pin 7 (SPEED IN) through an RC filter, preventing direction reversal while the motor is spinning quickly. In two-quadrant operation, this reversal can cause kinetic energy from the motor to be forced into the power MOSFETs.

A diode in series with the low-side MOSFETs facilitates PWM current control during braking by insuring that braking current will not flow backwards through low-side MOSFETs. Dual current-sense resistors give continuous current sense, whether braking or running in four-quadrant operation, an unnecessary luxury for two-quadrant operation.

The 68-k Ω and 3-nF tachometer components set maximum commutation time at 140 μ s. This permits smooth operation up to 35,000 RPM for four-pole motors, yet gives 140 μ s of noise blanking after commutation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9168902VYA	Active	Production	CDIP SB (JDJ) 28	12 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-9168902VY A UC1625-SP
5962-9168902VYA.A	Active	Production	CDIP SB (JDJ) 28	12 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-9168902VY A UC1625-SP

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

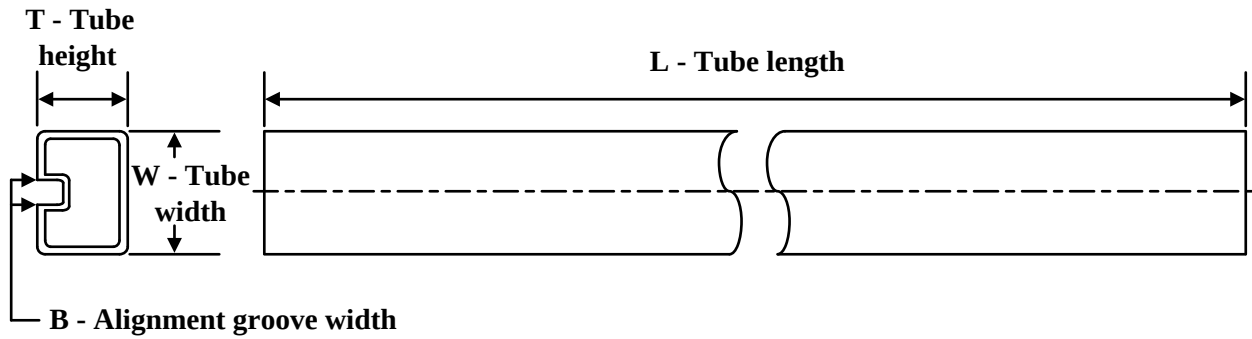
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TUBE

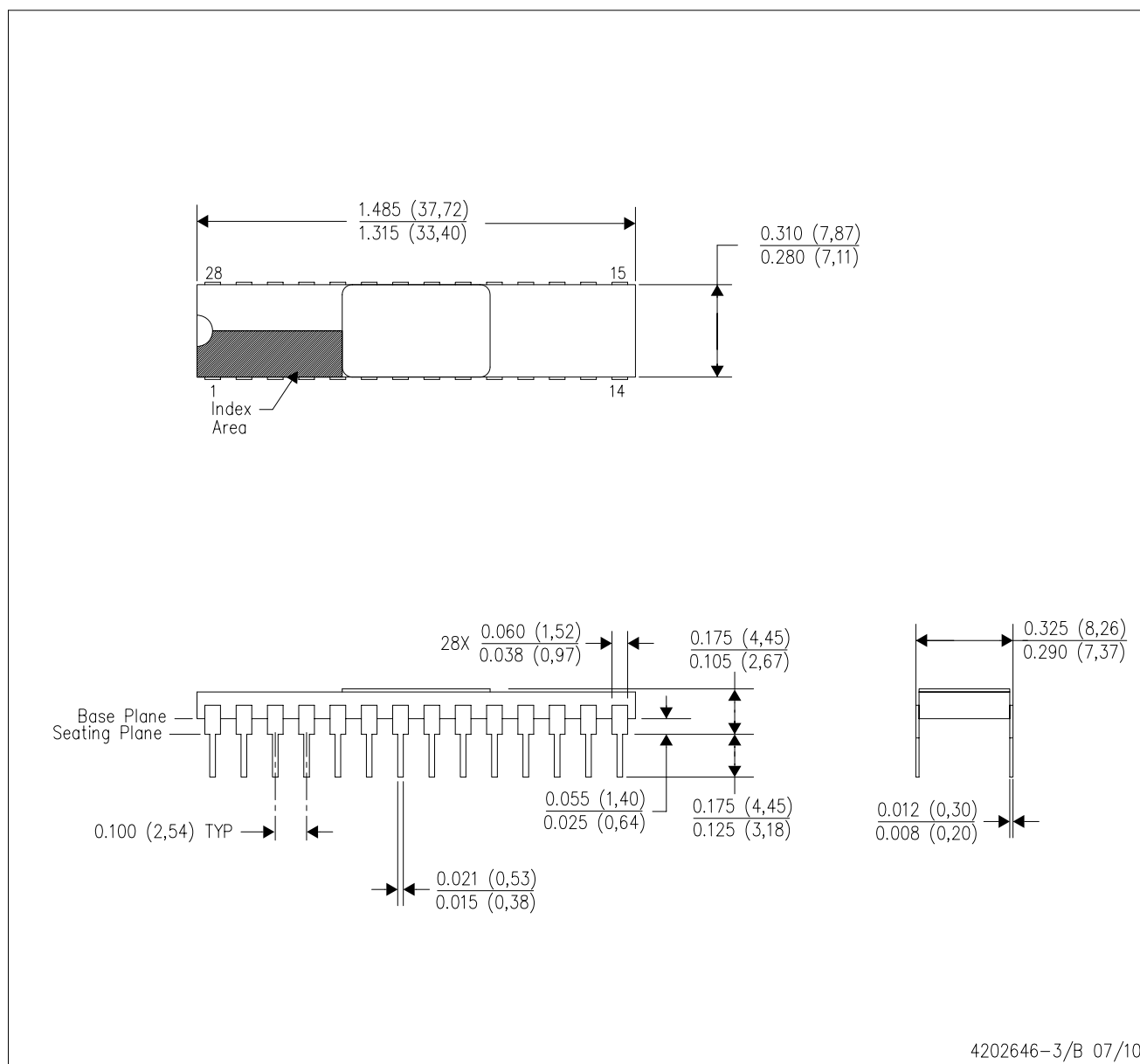


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9168902VYA	JDJ	CDIP SB	28	12	506.98	15.24	13440	NA
5962-9168902VYA.A	JDJ	CDIP SB	28	12	506.98	15.24	13440	NA

JDJ (R-CDIP-T28)

CERAMIC DUAL IN-LINE PACKAGE



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - Ceramic quad flatpack with flat leads brazed to non-conductive tie bar carrier.
 - This package is hermetically sealed with a metal lid.
 - The leads are gold plated and can be solderdipped.
 - Leads not shown for clarity purposes.
 - Lid and heat sink are connected to GND leads.

重要通知和免责声明

TI“按原样”提供技术和可靠性数据（包括数据表）、设计资源（包括参考设计）、应用或其他设计建议、网络工具、安全信息和其他资源，不保证没有瑕疵且不做任何明示或暗示的担保，包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任：(1) 针对您的应用选择合适的 TI 产品，(2) 设计、验证并测试您的应用，(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更，恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的相关应用。严禁以其他方式对这些资源进行复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务，TI 对此概不负责。

TI 提供的产品受 [TI 的销售条款](#) 或 [ti.com](#) 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址：Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
版权所有 © 2025，德州仪器 (TI) 公司